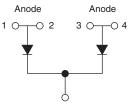
# VS-UFB310CB40



**Vishay Semiconductors** 

## Not Insulated SOT-227 Power Module **Ultrafast Rectifier, 310 A**





Base common cathode

PRIMARY CHARACTERISTICS							
V <sub>R</sub>	400 V						
$I_{F(AV)}$ at $T_{C}$ = 119 °C per module $^{(1)}$	310 A						
t <sub>rr</sub>	39 ns						
at T <sub>C</sub>	135 °C						
Туре	Modules - diode, FRED Pt®						
Package	SOT-227						

Note

(1) All 4 anode terminals connected

### **FEATURES**

- Not insulated package
- Ultrafast reverse recovery
- · Ultrasoft reverse recovery current shape
- Optimized for power conversion: welding and industrial SMPS applications
- · Plug-in compatible with other SOT-227 packages
- · Easy to assemble
- Direct mounting to heatsink
- Designed and gualified for industrial level
- UL approved file E78996
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **DESCRIPTION / APPLICATIONS**

The VS-UFB310CB40 not insulated modules integrate two state of the art ultrafast recovery rectifiers in the compact. industry standard SOT-227 package. The planar structure of the diodes, and the platinum doping life time control, provide a ultrasoft recovery current shape, together with the best overall performance, ruggedness and reliability characteristics.

These devices are thus intended for high frequency applications in which the switching energy is designed not to be predominant portion of the total energy, such as in the output rectification stage of welding machines, SMPS, DC/DC converters. Their extremely optimized stored charge and low recovery current reduce both over dissipation in the switching elements (and snubbers) and EMI/RFI.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Cathode to anode voltage	V <sub>R</sub>		400	V			
Continuous forward current per diode	I <sub>F</sub>	T <sub>C</sub> = 135 °C	155	А			
Single pulse forward current per diode	I <sub>FSM</sub> <sup>(1)</sup>	$T_{\rm C} = 25 \ ^{\circ}{\rm C}$	1300	A			
Maximum power dissipation per module	PD	T <sub>C</sub> = 135 °C	421	W			
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C			

#### Note

(1) 10 ms sine or 6 ms rectangular pulse

COMPLIANT



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<b>ELECTRICAL SPECIFICATIONS PER DIODE</b> ( $T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		TYP.	MAX.	UNITS	
Cathode to anode breakdown voltage	V <sub>BR</sub>	I <sub>R</sub> = 100 μA	400	-	-		
		I <sub>F</sub> = 100 A	-	1.11	1.34		
		$I_F = 100 \text{ A}, T_J = 125 ^\circ\text{C}$	-	0.99	1.1		
Forward voltage, per leg	$V_{FM}$	$I_F = 100 \text{ A}, T_J = 175 \text{ °C}$	-	0.97	-	V	
		I <sub>F</sub> = 200 A	-	1.3	1.6		
		I <sub>F</sub> = 200 A, T <sub>J</sub> = 125 °C	-	1.22	1.4		
		I <sub>F</sub> = 200 A, T <sub>J</sub> = 175 °C	-	1.25	-		
		$V_{R} = V_{R}$ rated	-	1.3	50		
Reverse leakage current, per leg	I <sub>RM</sub>	$V_R = V_R$ rated, $T_J = 125 \ ^\circ C$	-	100	-	μA	
		$V_R = V_R$ rated, $T_J = 175 \ ^\circ C$	-	1	4	mA	
Junction capacitance, per leg	CT	V <sub>R</sub> = 400 V	-	100	-	pF	

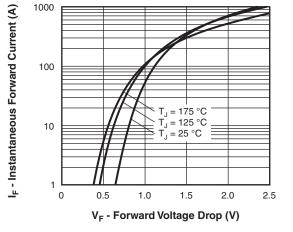
<b>DYNAMIC RECOVERY CHARACTERISTICS PER DIODE</b> ( $T_J$ = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CC	MIN.	TYP.	MAX.	UNITS		
		I <sub>F</sub> = 1.0 A, dI <sub>F</sub> /dt = 400 A/µs, V <sub>F</sub>		-	39	-		
Reverse recovery time, per leg	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	89	-	ns	
		T <sub>J</sub> = 125 °C		-	184	-		
Poole recovery ourrent per leg	r recovery current, per leg I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 50 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 200 V	-	9	-	٨	
Peak recovery current, per leg		T <sub>J</sub> = 125 °C		-	20	-	A	
	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	400	-		
Reverse recovery charge, per leg		T <sub>J</sub> = 125 °C		-	1840	-	nC	

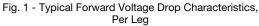
THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C	
Junction to case, single leg conducting	Р		-	-	0.19		
Junction to case, both leg conducting	R <sub>thJC</sub>		-	-	0.095	°C/W	
Case to heatsink	R <sub>thCS</sub>	Flat, greased surface	-	0.07	-		
Weight			-	30	-	g	
Mounting torque		Torque to terminal	-	-	1.1 (9.7)	Nm (lbf.in)	
Mounting torque		Torque to heatsink	-	-	1.8 (15.9)	Nm (lbf.in)	
Case style				SOT-227	' not insulate	ed	

# VS-UFB310CB40

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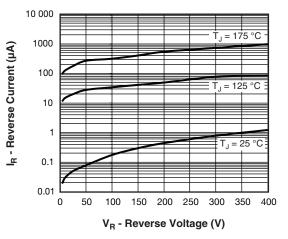
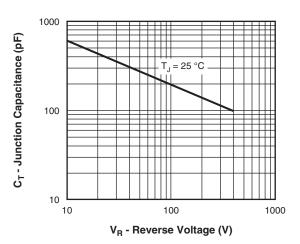
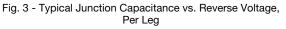


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage, Per Leg





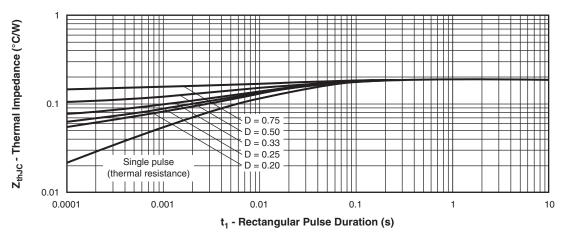
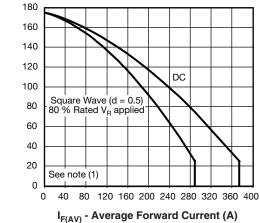


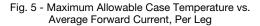
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics, Per Leg

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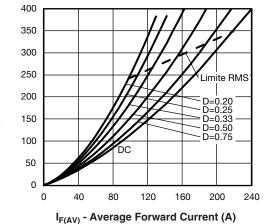


Fig. 6 - Forward Power Loss Characteristics, Per Leg

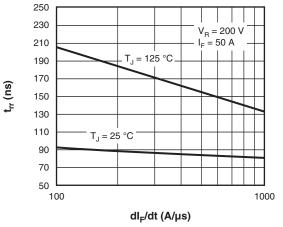
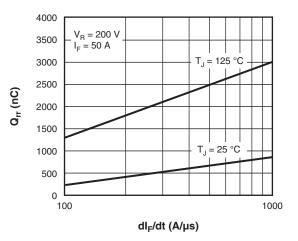
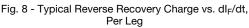


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt, Per Leg





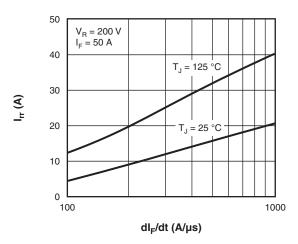


Fig. 9 - Typical Reverse Recovery Current vs. dl<sub>F</sub>/dt, Per Leg

Average Power Loss (W)

Allowable Case Temperature (°C)

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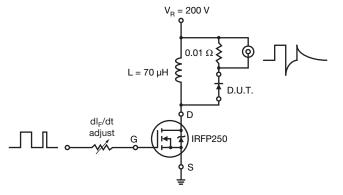


Fig. 10 - Reverse Recovery Parameter Test Circuit

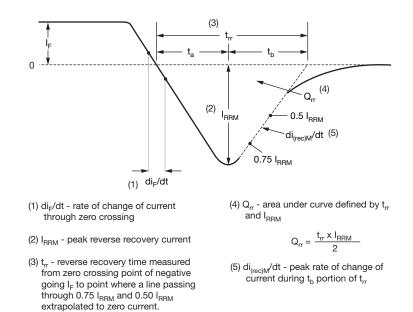


Fig. 11 - Reverse Recovery Waveform and Definitions

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### **ORDERING INFORMATION TABLE**

Device code	VS-	UF	В	310	С	В	40	
		2	3	4	5	6	(7)	
	1 - 2 - 3 - 4 - 5 - 6 -	Ultra Ultra Cur Circ	afast rec afast Pt rent rationalise	diffused ng (310 iguratior	= 310 A n (two di	() Jodes co		cathode) insulated)

Quantity per tube is 10 pcs, M4 screw and washer included

CIRCUIT CONFIGURATION						
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING				
Two diodes common cathode	С	Lead Assignment				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95423				
Packaging Information	www.vishay.com/doc?95425				

**Vishay Semiconductors** 



SOT-227 Generation 2

#### **DIMENSIONS** in millimeters (inches)



#### Note

• Controlling dimension: millimeter



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